Product data sheet Characteristics

XUVR1212PANM8

photo-electric sensor - XUV - fork - 120X120mm - 12..24VDC - M8

Commercial Status	Commercialised
Range of product	OsiSense XU
Series name	General purpose
Electronic sensor type	Photo-electric sensor
Sensor name	XUVR
Sensor design	Fork
Detection system	Thru beam
Emission	Red LED, modulated
Passage width	120 mm
Passage depth	120 mm
Material	Metal/Plastic
Supply circuit type	DC
Wiring technique	3-wire
Discrete output type	PNP
Discrete output function	1 NO
Electrical connection	1 male connector M8, 3 pins
Product specific application	Detection on small conveyor
[Sn] nominal sensing distance	120 mm

Complementary

Enclosure material	Painted aluminium and polyamide/glass	
Spot diameter	0.8 mm	
Type of output signal	Discrete	
Output type	Solid state	
Status LED	1 LED (yellow) for output state	
[Us] rated supply voltage	1224 V DC with reverse polarity protection	
Supply voltage limits	1030 V DC	
Switching capacity in mA	100 mA (overload and short-circuit protection)	
Switching frequency	4000 Hz	
Voltage drop	<= 1.5 V (closed state)	
Current consumption	< 20 mA (no-load)	
Product weight	0.080.19 kg	

Environment

Product certifications	CE	
	CSA	
	UL	
Ambient air temperature for operation	-1060 °C	
Ambient air temperature for storage	-4080 °C	
Immunity to ambient light	5000 lux with incandescent bulb	
	10000 lux with natural light	
Vibration resistance	7 gn, amplitude = +/- 0.75 mm (f = 1055 Hz) conforming to IEC 60068-2-6	
Shock resistance	30 gn (duration = 11 ms) conforming to IEC 60068-2-27	
IP degree of protection	IP67	
	IP65	

Period 18 months

